

**Nov. 16<sup>th</sup>, 2011**

# **Evaluation Technology of Practical Electric Properties for High Frequency Materials**

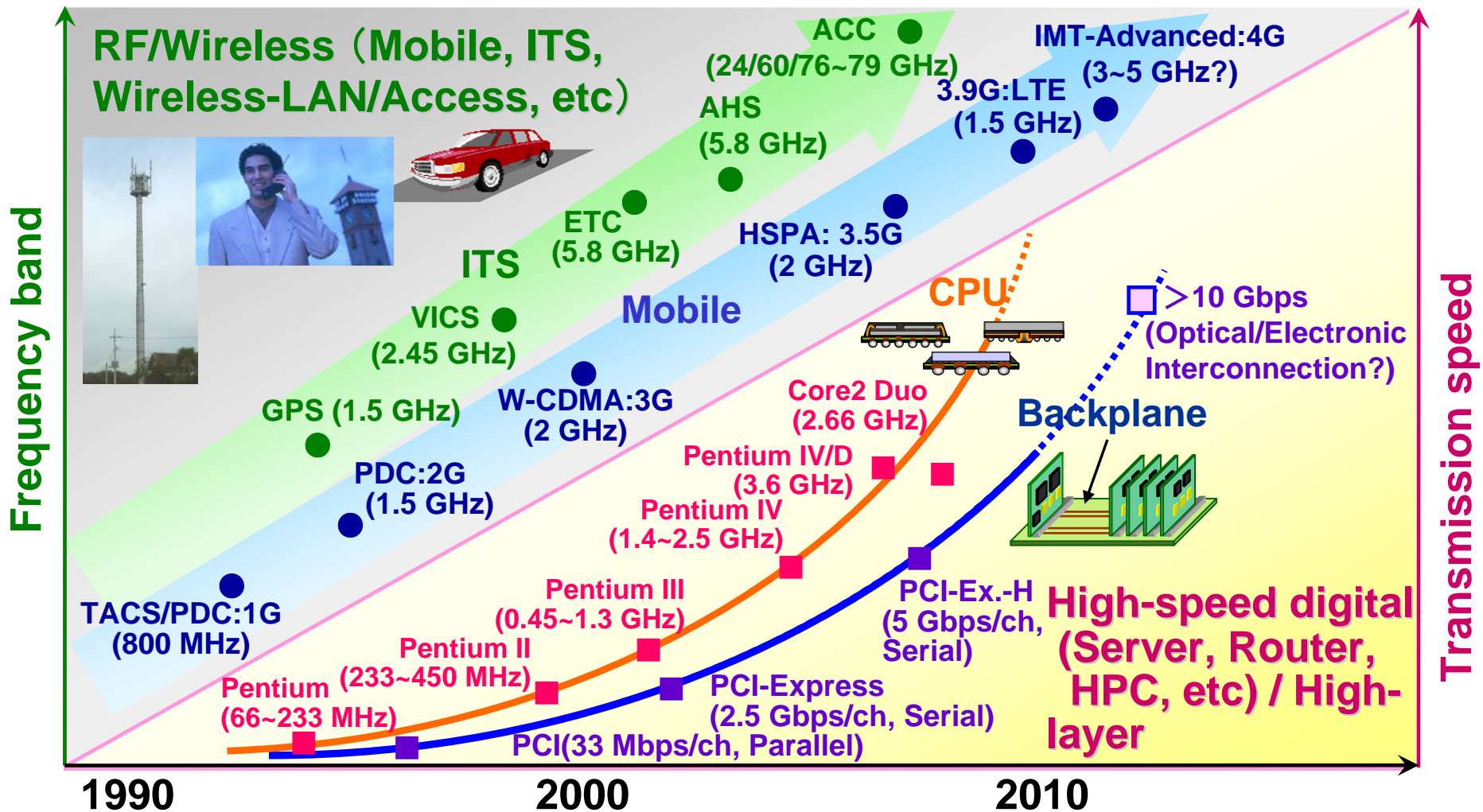
**Yusuke Kondo, Hikari Murai  
Tetsuro Irino, Hiroshi Shimizu**

**Tsukuba Research Laboratory  
Telecommunication Materials Development Center**

**Printed Wiring Board Materials R&D Dept.  
Printed Wiring Board Materials Business Sector**

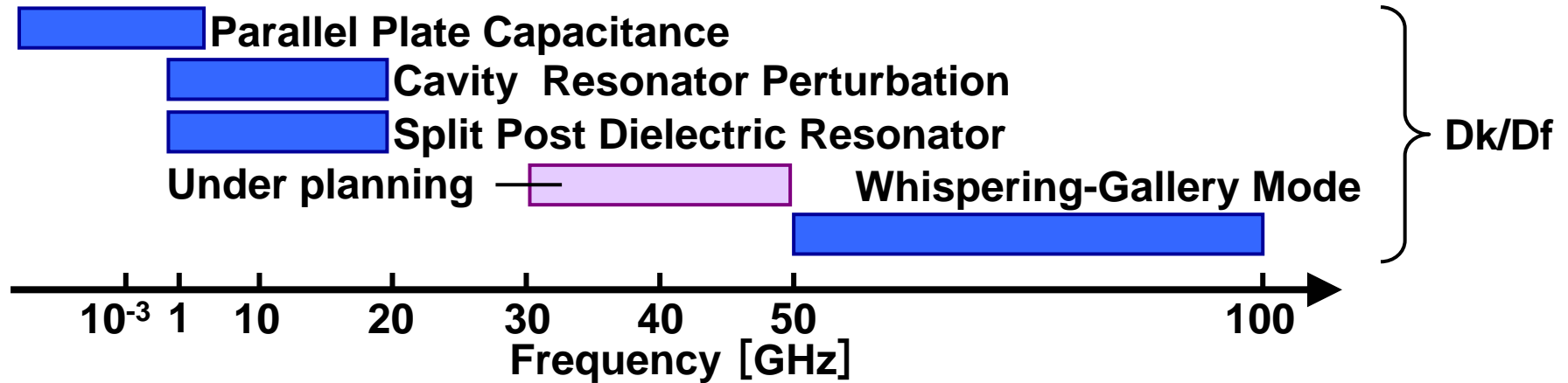
 **Hitachi Chemical Co., Ltd.**

# Trend of high-Speed & high-frequency applications

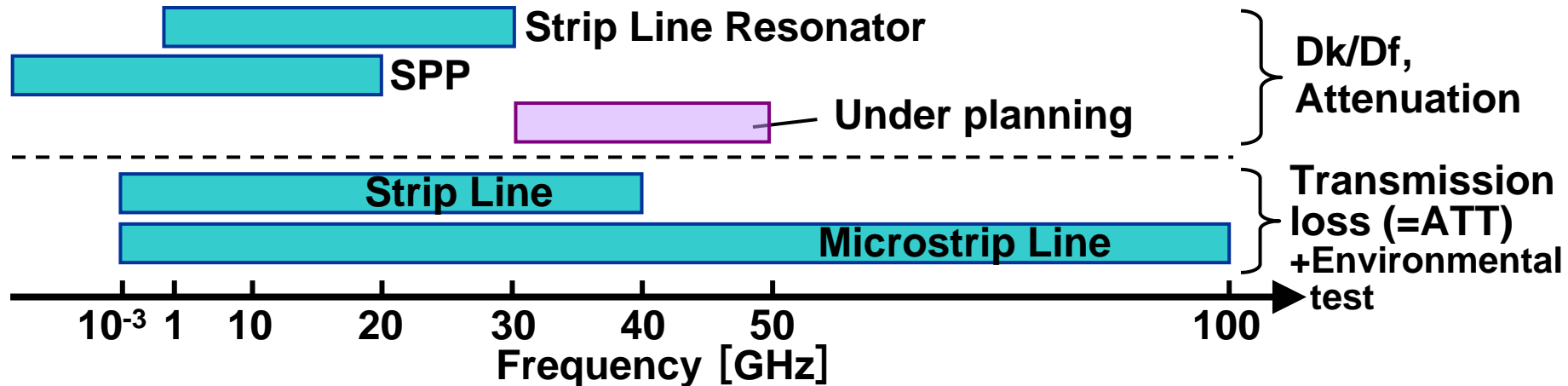



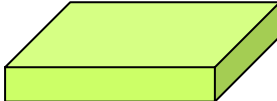

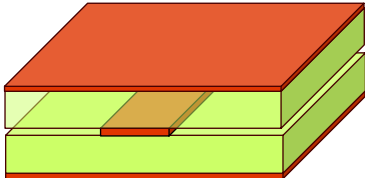
## Hitachi Chemical can satisfy various evaluation requirements

### Dielectric properties of materials



### Practical electrical properties of PCB

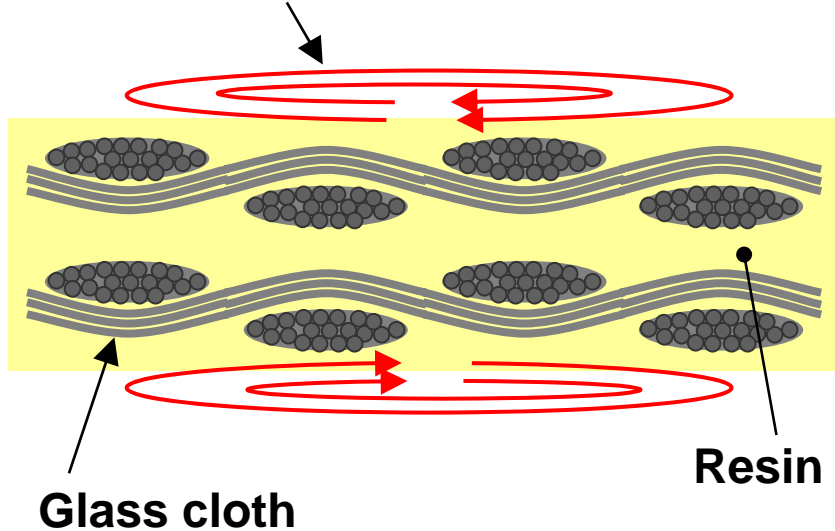


Subject	Material			PCB
Method	Cavity Resonator Perturbation	Split Post Dielectric Resonator	WG mode dielectric resonator	Strip Line Resonator
Freq.	1 ~ 20 GHz	1 ~ 20 GHz	50 ~ 100 GHz	1 ~ 30 GHz
Sample form	 <ul style="list-style-type: none"> <li>▪ w/o conductor</li> <li>▪ Stick</li> <li>▪ Thickness : ~ 1 mm</li> <li>▪ Width: 1~2 mm</li> <li>▪ Length: 80 mm</li> </ul>	 <ul style="list-style-type: none"> <li>▪ w/o conductor</li> <li>▪ Sheet / board</li> <li>▪ Thickness : ~ 0.5 mm</li> <li>▪ Width : 10 ~ 130 mm</li> </ul>	 <ul style="list-style-type: none"> <li>▪ w/o conductor</li> <li>▪ Disk</li> <li>▪ Thickness : ~ 2 mm</li> <li>▪ Diameter : 30 ~ 60 mm</li> </ul>	 <ul style="list-style-type: none"> <li>▪ Strip line</li> <li>▪ Thickness : <math>\geq 1.0</math>mm</li> <li>▪ Characteristic impedance: 50 <math>\Omega</math></li> </ul>
Standard	JIS C-2565	—	Under planning	IPC-TM-650 2.5.5.5.1 JPCA-TM001-2007

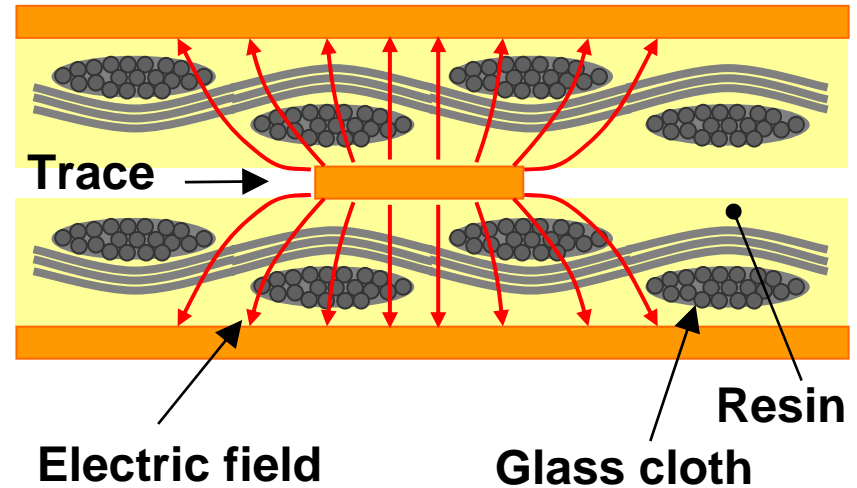
- Various methods exist to evaluate dielectric properties of materials and PCBs.
- Usable frequency band and sample form are different.

## Split Post Dielectric Resonator

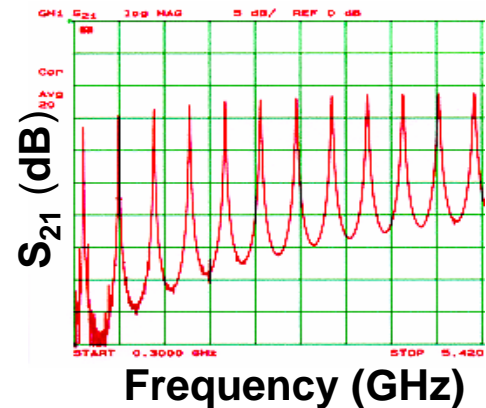
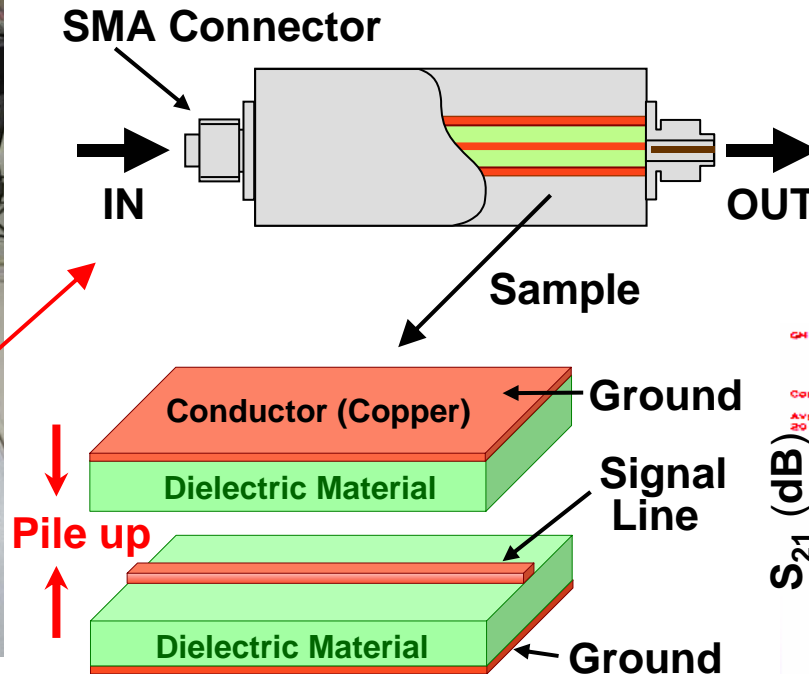
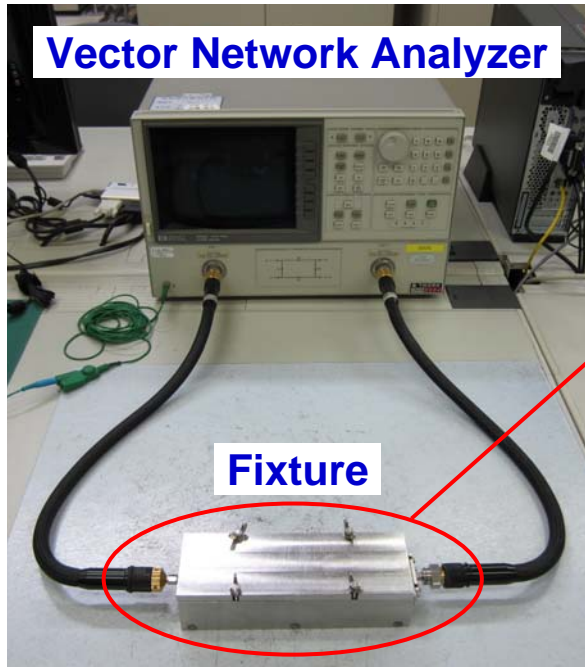
Electric field (occur on surface)



## Strip Line Resonator



- PCB materials have anisotropy because of difference of  $D_k$  between resin and glass cloth.
- Suitable methods are utilized to evaluate anisotropic dielectric properties and practical electric properties of materials depending on frequency band and application of materials.



Periodic resonance frequencies  $\Rightarrow$  Calculation  $\Rightarrow$  Dk  
 Transmission curve,  $S_{21}$   $\Rightarrow$  Calculation  $\Rightarrow$  Attenuation, Df  
 (Original conversion method)

- Frequency domain method
- Capable of measuring properties of thermal drift and moisture absorption drift

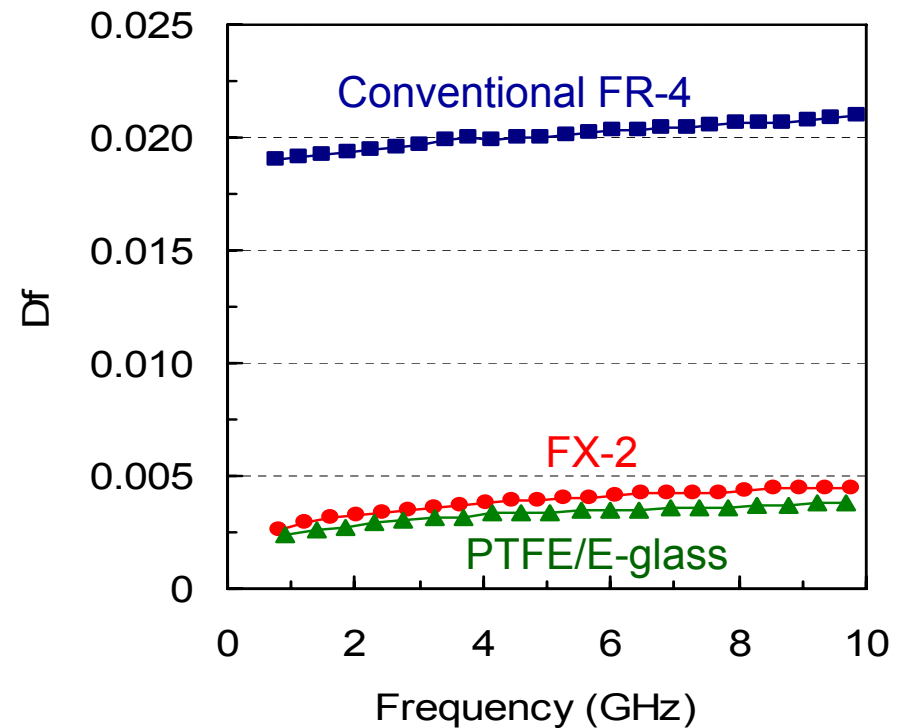
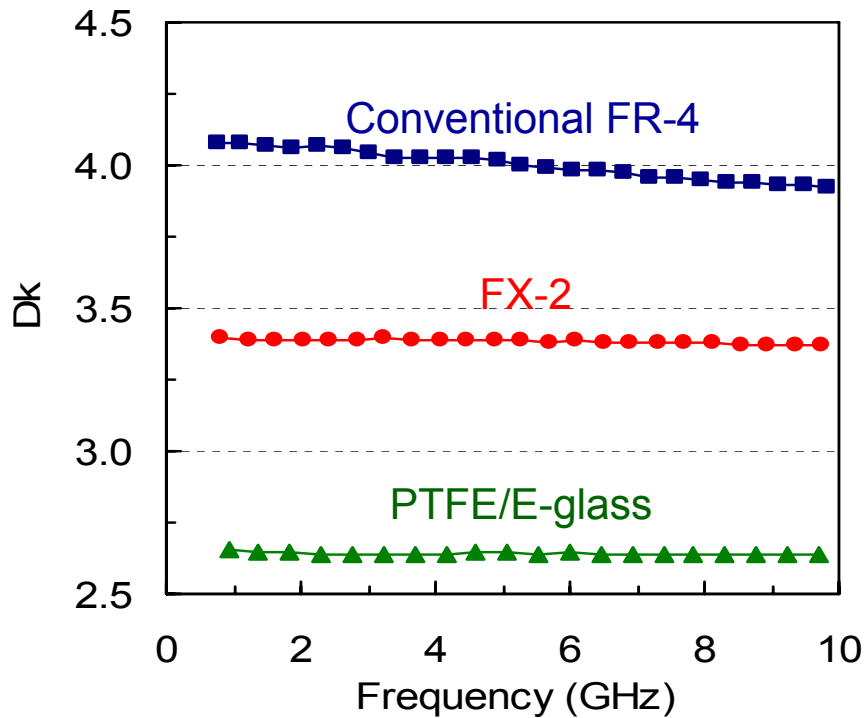
## < Measurement conditions >

/ Method: Strip Line Resonator by Vector Network Analyzer/JPCA TM001/IPC-TM-650\_2.5.5.5.1

/ Temperature & humidity: 25 °C/ 60 %RH

/ Laminate thickness: 0.8 mm (signal-ground distance: 0.8 mm), copper foil: 18  $\mu$ m

/ Line width: 1 mm



**Good stability of dielectric properties in wide frequency bands**

## < Measurement conditions >

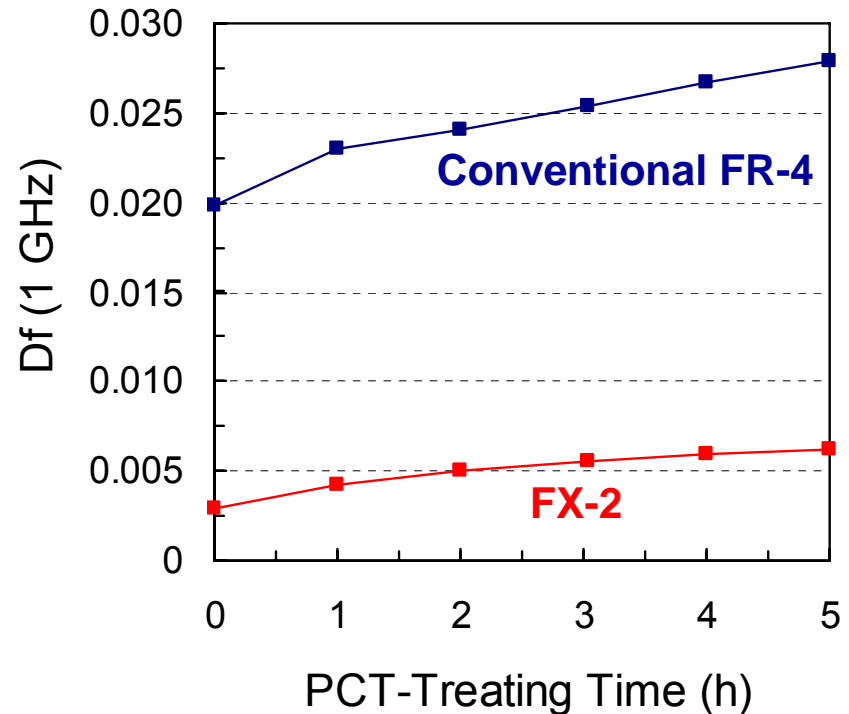
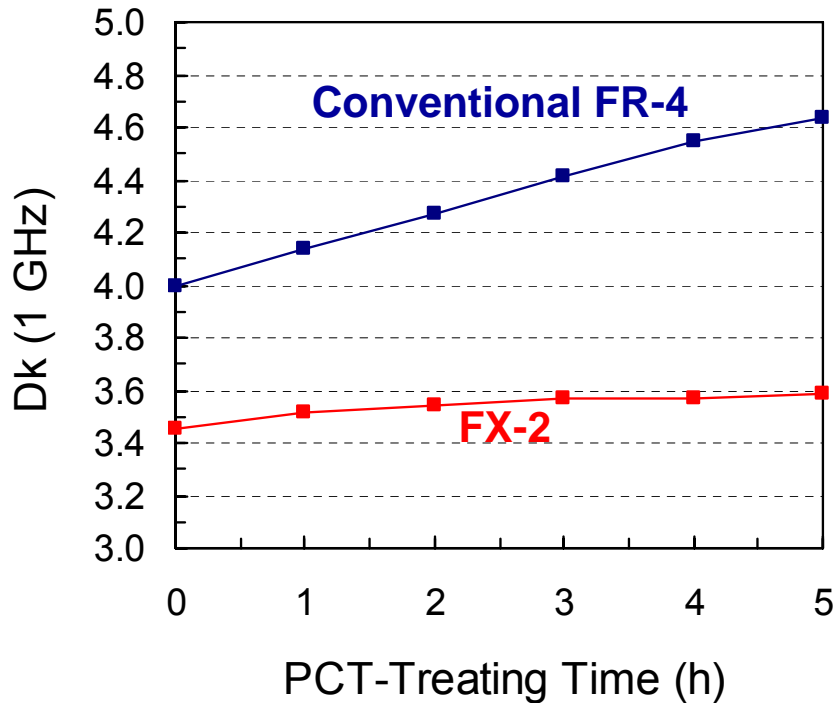
/ Method: Strip Line Resonator by Vector Network Analyzer/JPCA TM001/IPC-TM-650 2.5.5.5.1

/ Moisture treatment condition: PCT(121°C/0.22 MPa)-1~5 h

/ Temperature : 25 °C

/ Laminate thickness: 1.6 mm (signal-ground distance: 0.8 mm), copper foil:18 μm

/ Line width: 1 mm



**Stable Dk & Df against PCT treatment compared with FR-4**



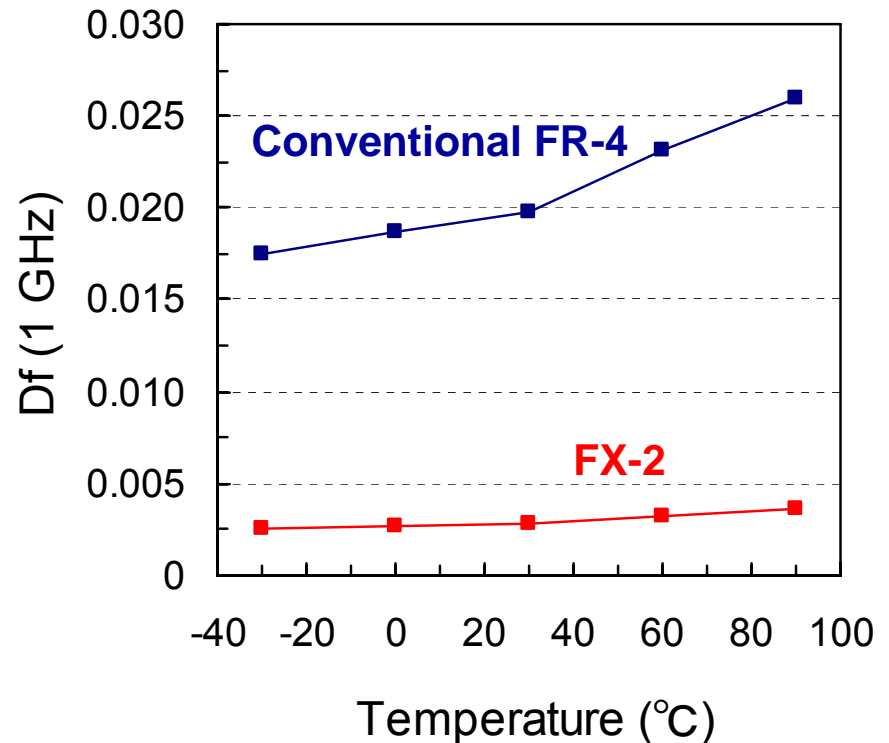
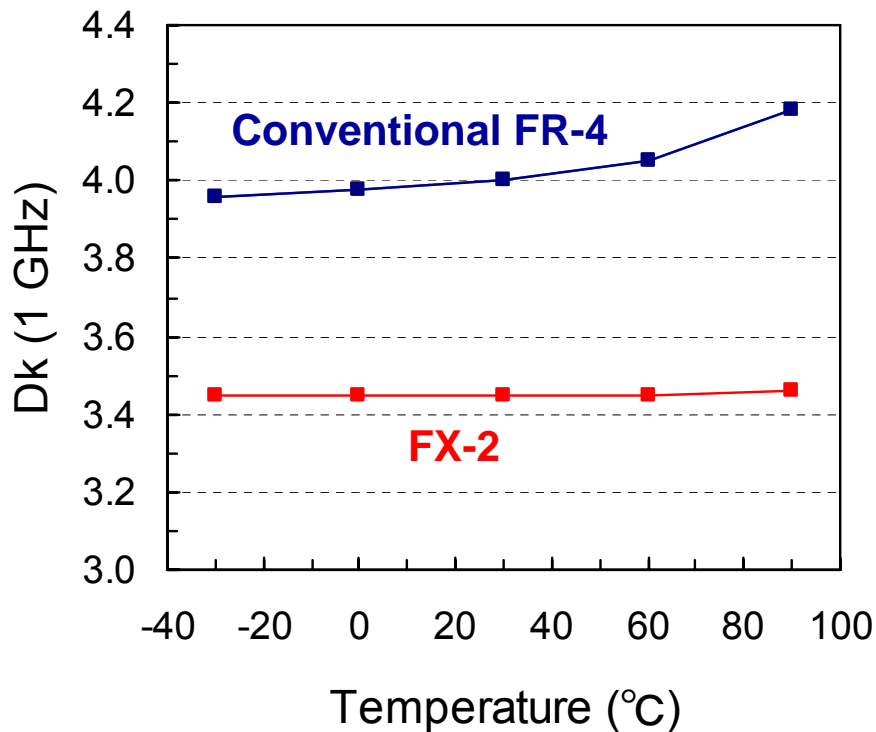
## < Measurement conditions >

/ Method: Strip Line Resonator by Vector Network Analyzer/JPCA TM001/IPC-TM-650 2.5.5.5.1

/ Temperature: -30~90°C

/ Laminate thickness: 1.6 mm (signal-ground distance: 0.8 mm), copper foil: 18 μm

/ Line width: 1 mm



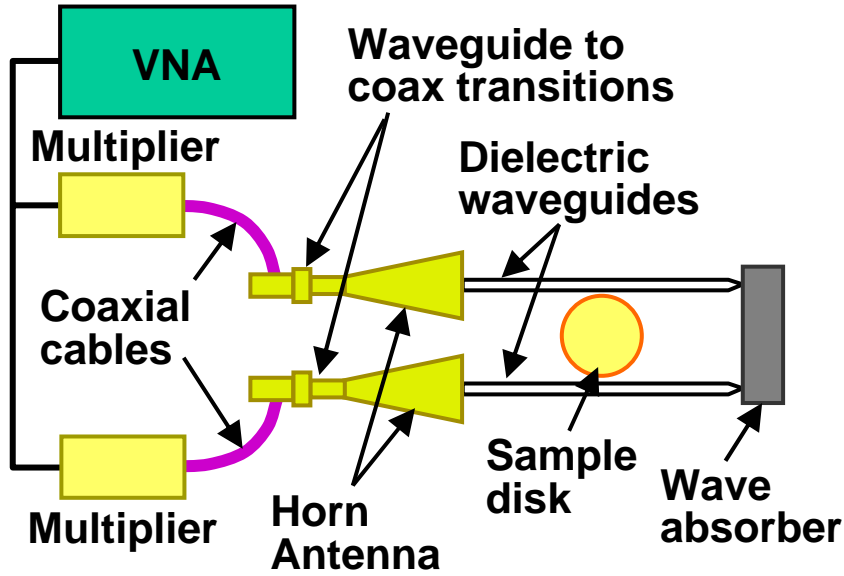
**Good stability of dielectric properties against temperature**

## Test vehicle / SMASPP2z

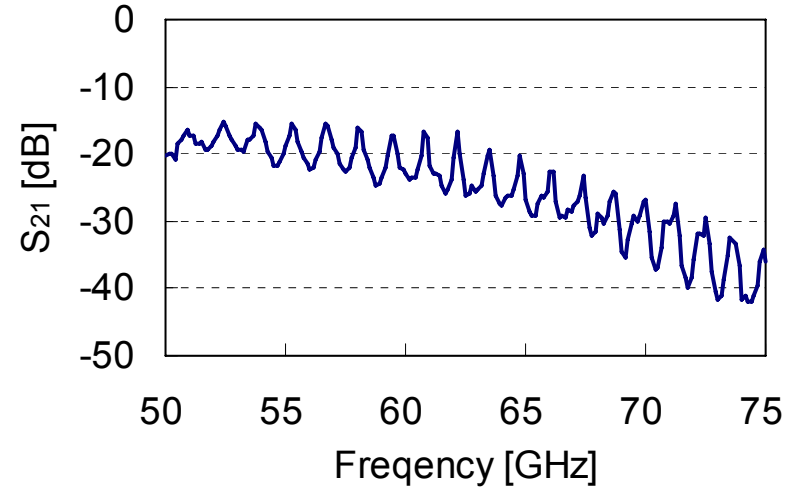
Category	Frequency	FX-2		HE-679G	
		Resin rich, PF	Resin poor, LP	Resin rich, RTF	Resin poor, LP
Dk	1 GHz	3.12	3.48	3.67	3.95
	3 GHz	3.11	3.47	3.63	3.92
	10 GHz	3.09	3.45	3.59	3.88
	20 GHz	3.09	3.44	3.56	3.86
Df	1 GHz	0.0050	0.0054	0.0148	0.0115
	3 GHz	0.0053	0.0058	0.0161	0.0124
	10 GHz	0.0053	0.0062	0.0165	0.0125
	20 GHz	0.0064	0.0074	0.0169	0.0134

- Hitachi Chemical is certificated as an evaluator of SPP
- SPP assessment is useful to accelerate R&D of materials because we can know performance of materials including influence of copper foils

## ● Measurement system



## ● Resonance wave form

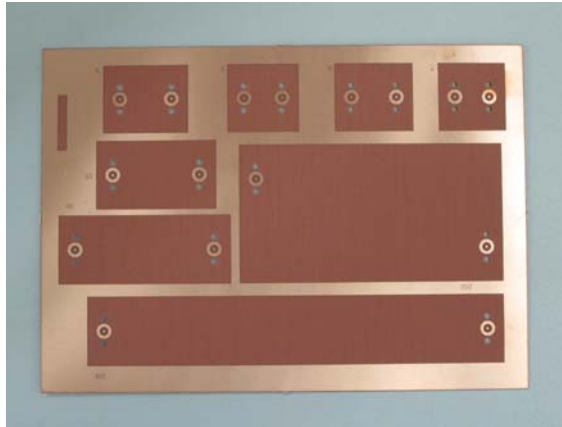


## ● Dielectric properties (@60 GHz)

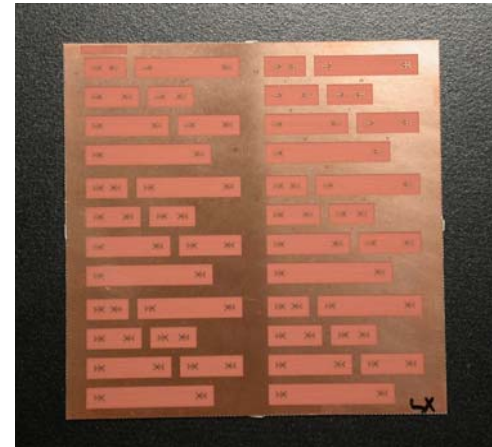
Material	Dk	Df
HE- 679G	4.16	0.0096
LZ- 71G	3.68	0.0069
FX- 2	3.52	0.0039
E- 700G(R)	4.61	0.0101
E- 800G(L)	3.91	0.0078

Dielectric properties can be measured in millimeter wave band

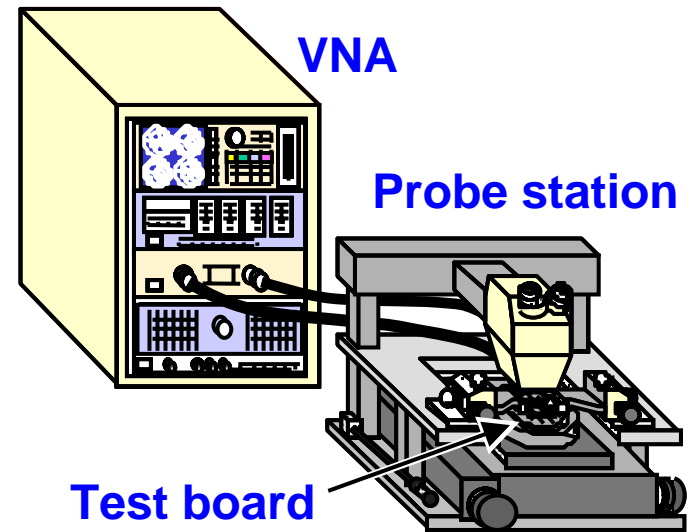
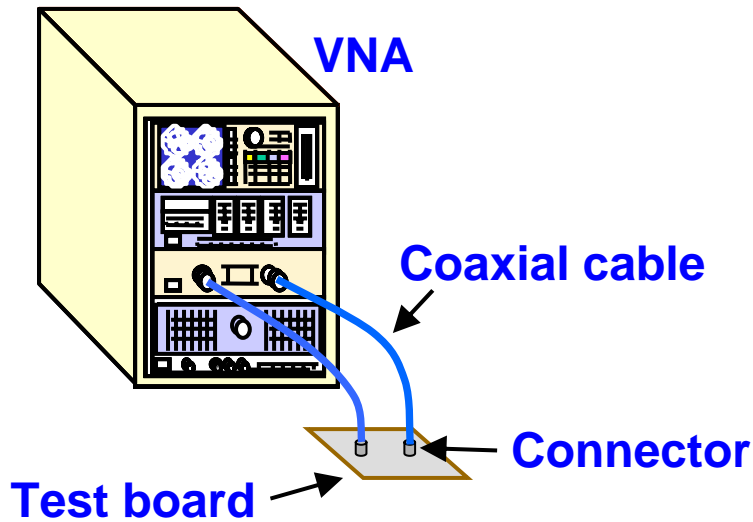
## ● Measurement of Strip line



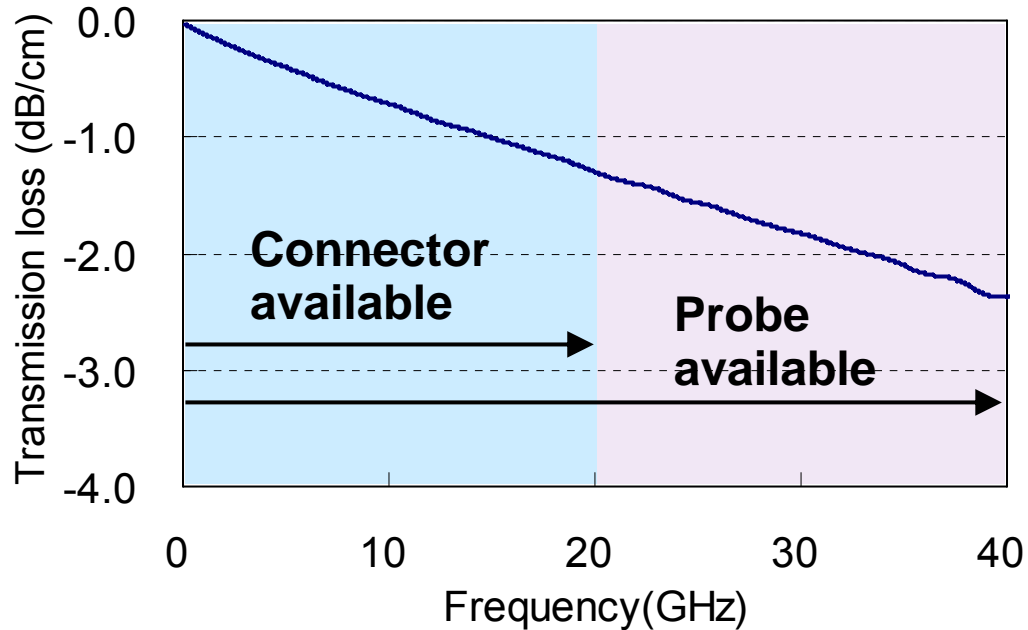
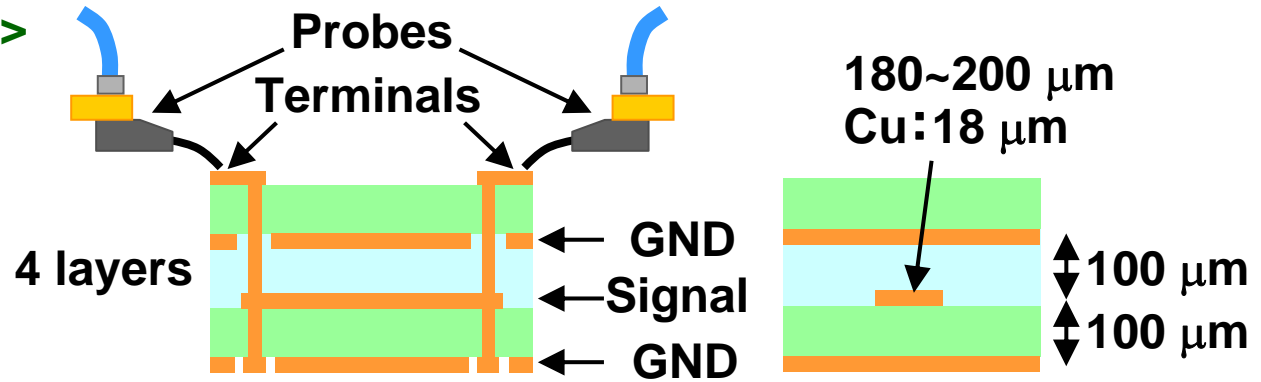
Test board (up to 20 GHz)



Test board (up to 40 GHz)

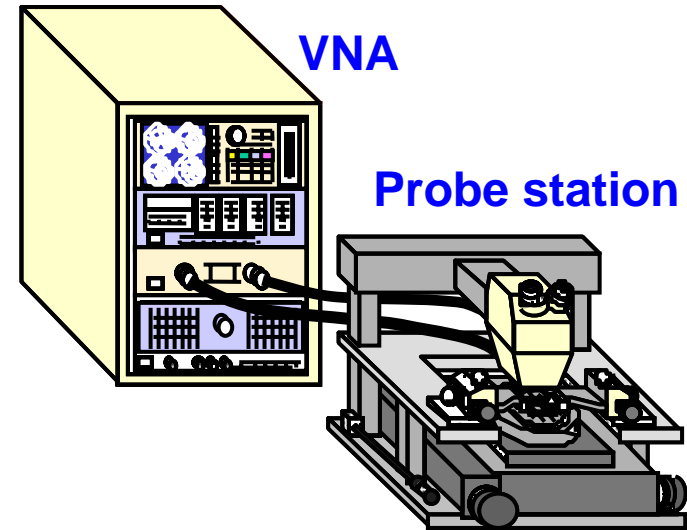
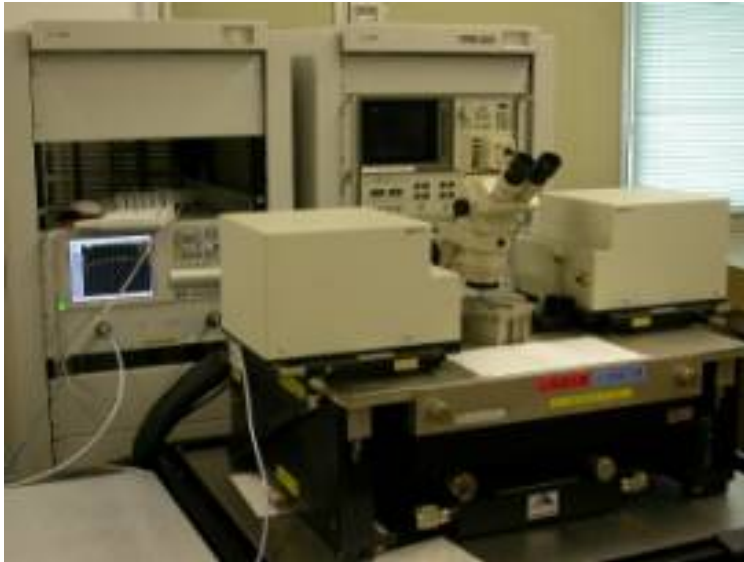


<Measurement condition>  
/ Structure: strip line  
/ Equipment: VNA  
/ Calibration: TRL

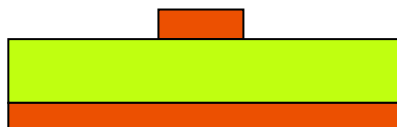


Capable of evaluating strip line up to approximately 40 GHz

## Evaluation system for semi-microwave ~ milliwave properties



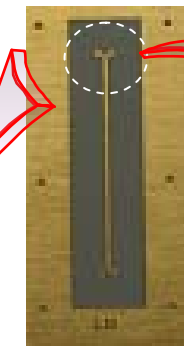
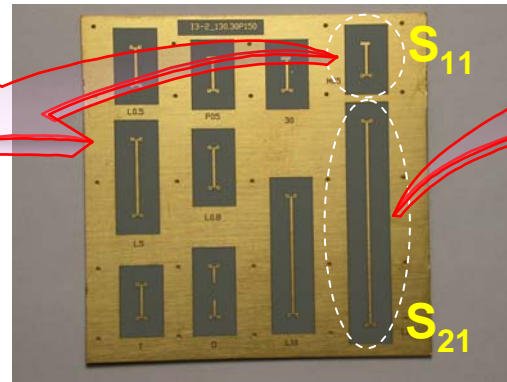
## TEG PWB for evaluation (microstrip line structure)



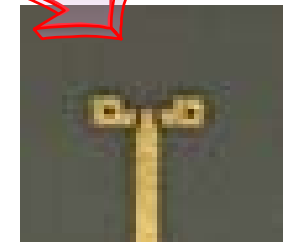
Cross section of TEG



Pattern for S11



Pattern for S21

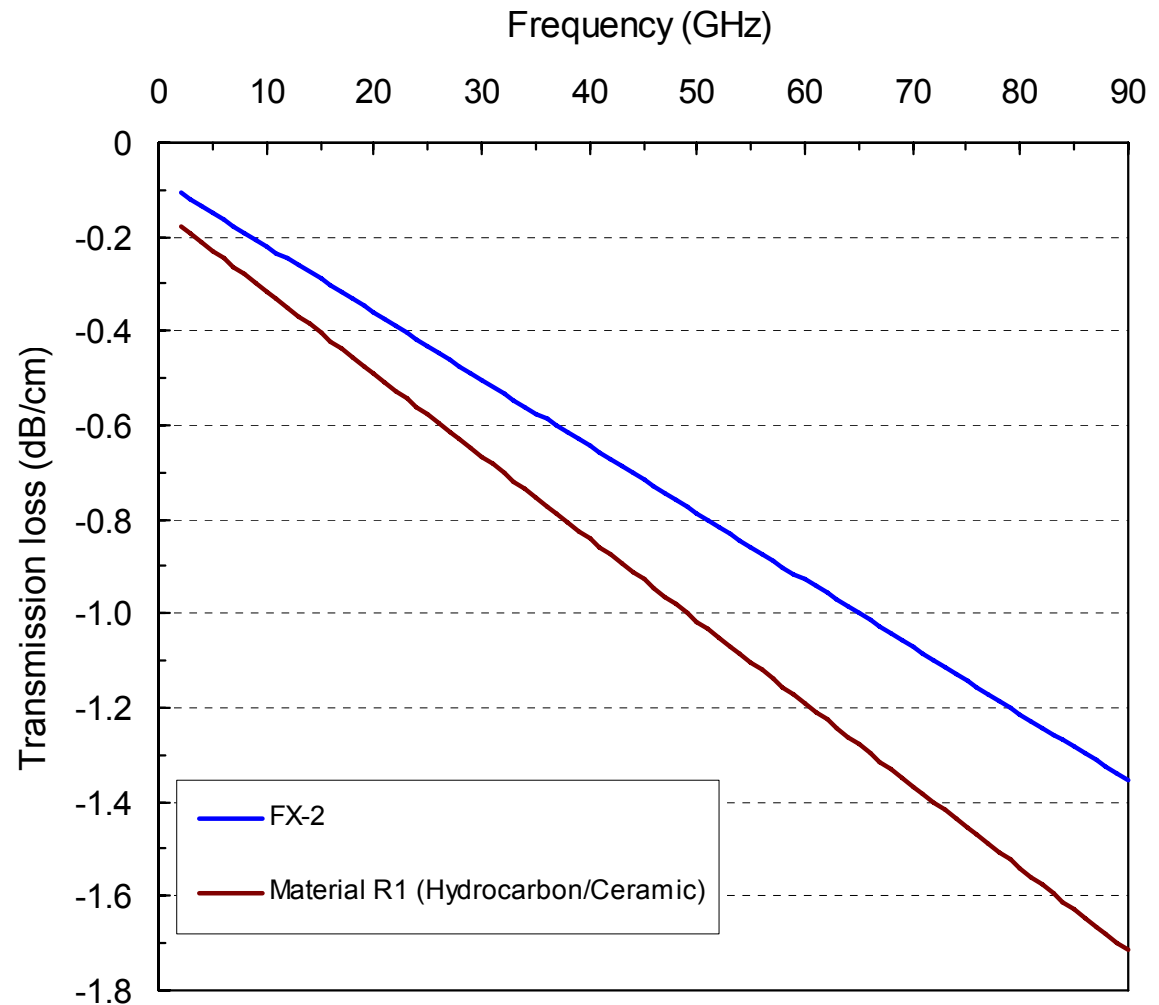
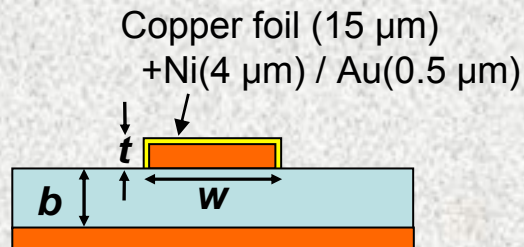


Measurement terminal

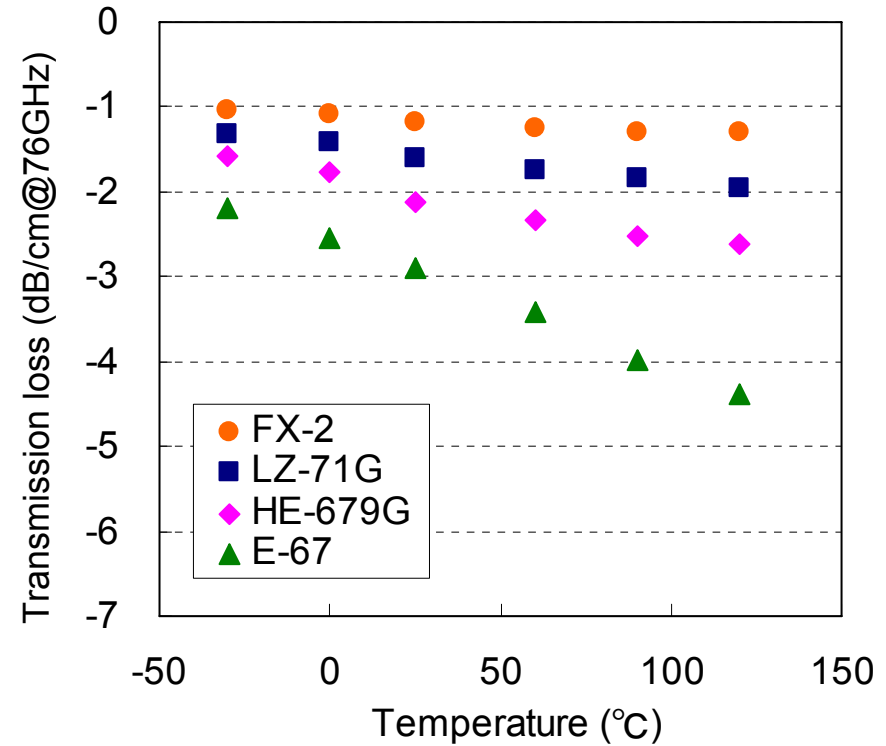
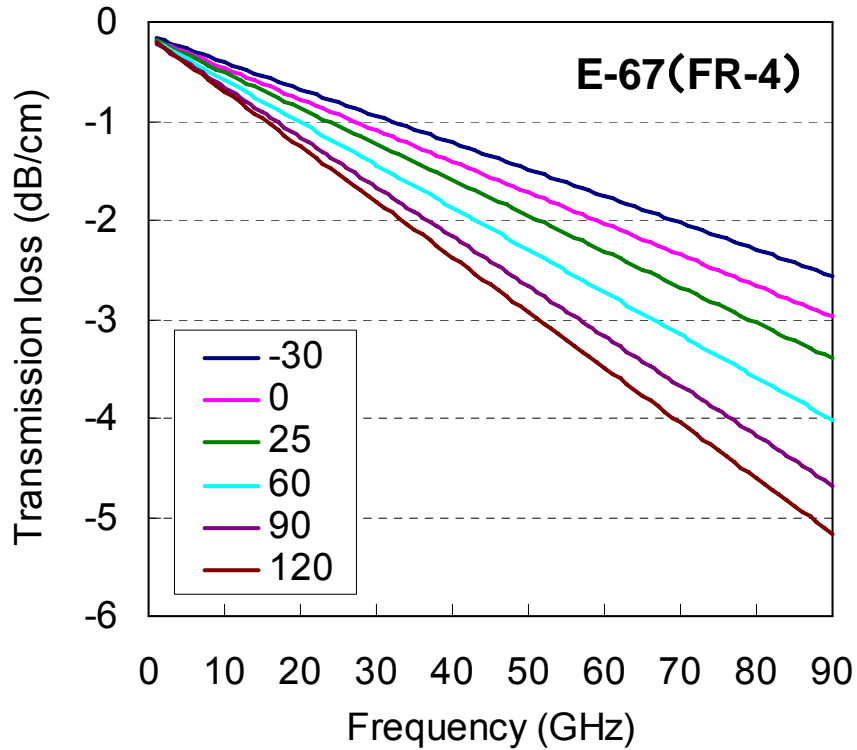
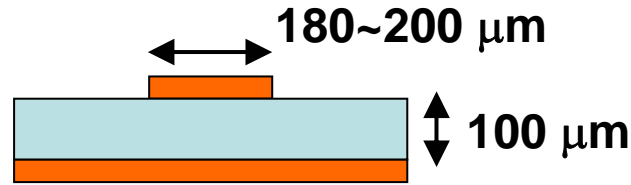
## Transmission loss (1 ~ 90GHz, S<sub>21</sub>@MSL)

### < Measurement conditions >

- / Structure: microstrip line
- / Temperature & humidity: 25°C/40%RH
- / Characteristic impedance: 50 Ω
- / Calibration: TRL
- / Dimension parameters
  - Line width ( $w$ ): 0.2 ~ 0.22 mm
  - Dielectric thickness ( $b$ ): 0.1 ~ 0.13 mm
  - Copper thickness ( $t$ ): 18 μm
  - Line length: 10 mm & 20 mm
  - Surface treatment of copper: Ni(4 μm)/Au(0.5 μm) plating



<Measurement condition>  
/ Structure: microstrip line  
/ Equipment: VNA  
/ Calibration: SOLT

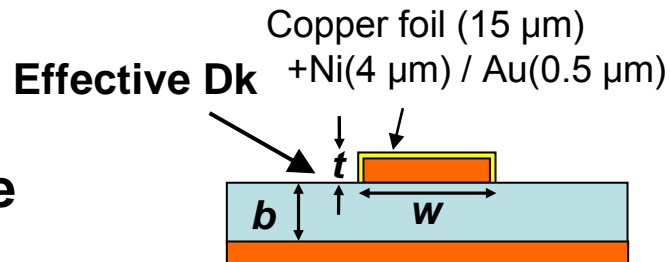


**High frequency materials have good stability of transmission loss against temperature**



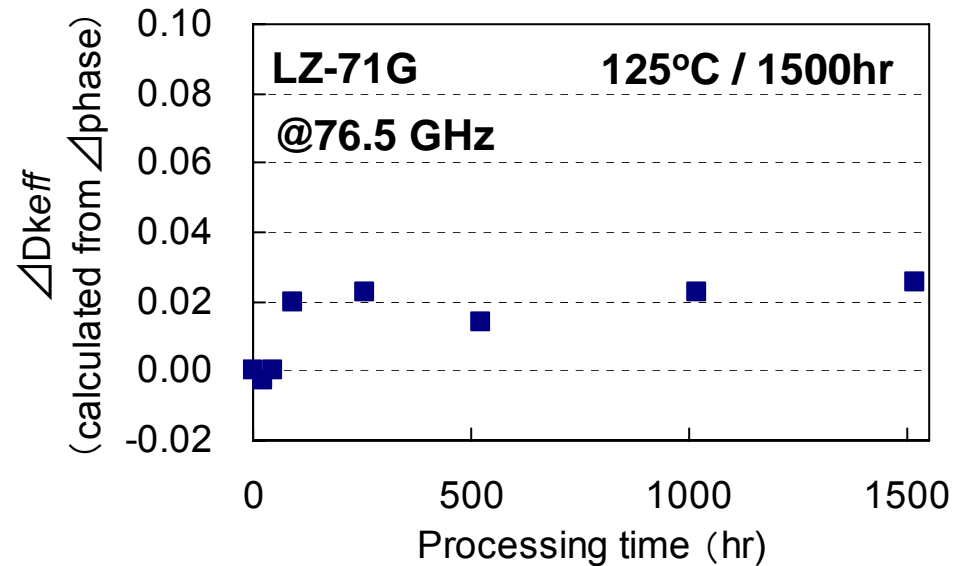
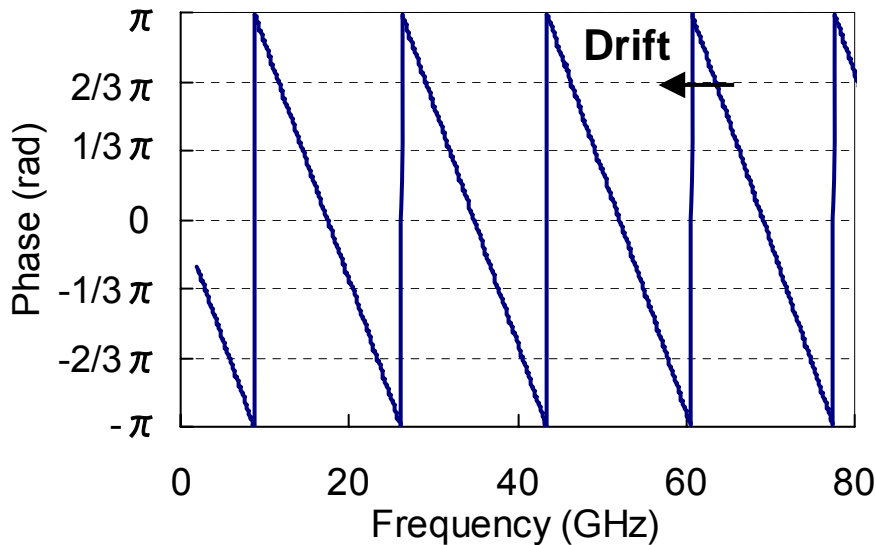
## Influence of heat-processing

Effective Dk can be calculated from phase



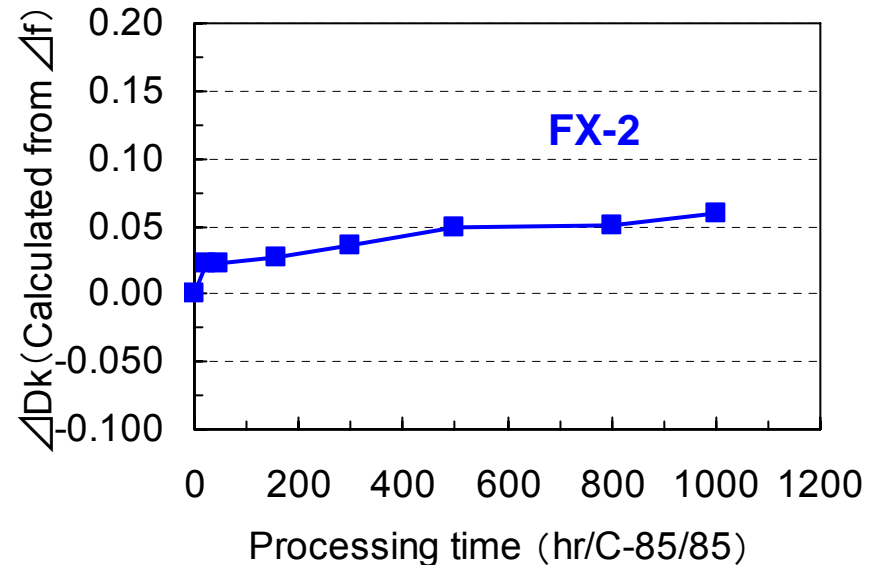
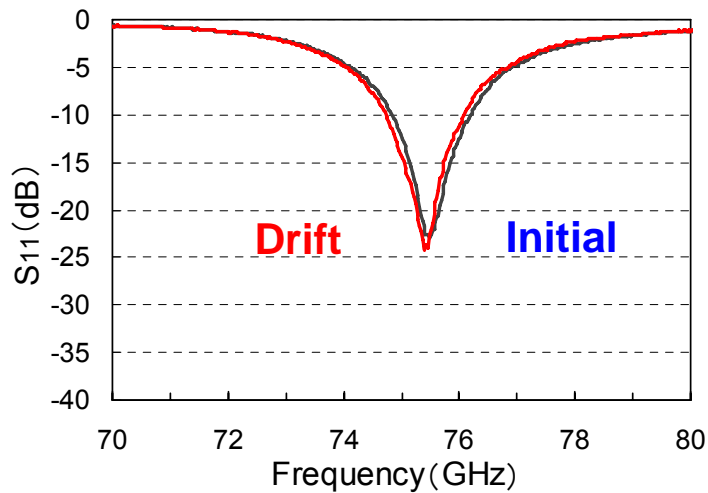
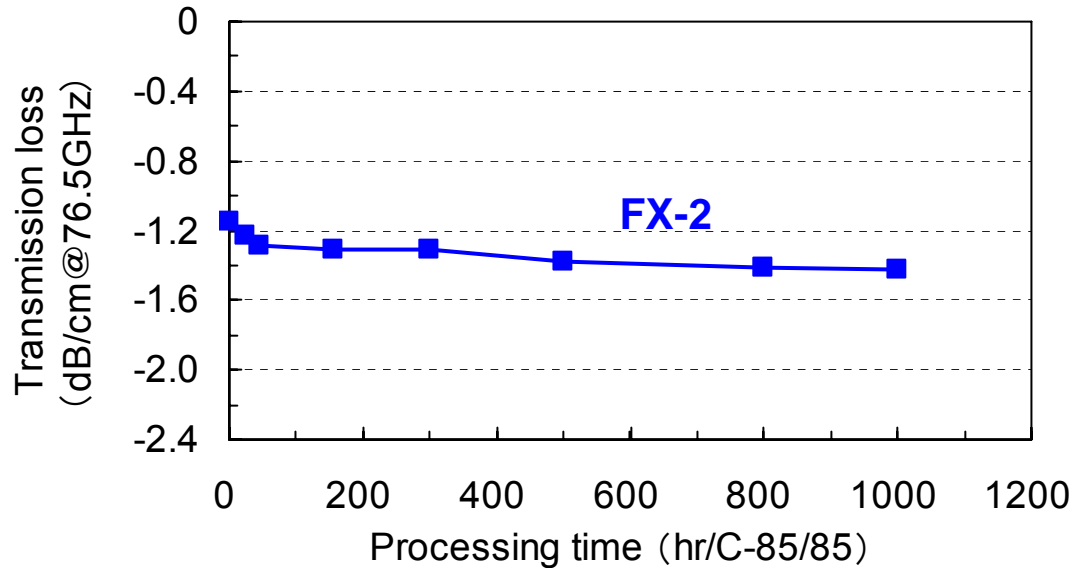
- Line width( $w$ ): 0.2 ~ 0.22 mm
- Dielectric thickness( $b$ ): 0.1 ~ 0.13 mm
- Copper thickness( $t$ ): 18  $\mu\text{m}$
- Line length: 10 mm & 20 mm
- Surface treatment of copper: Ni(4  $\mu\text{m}$ )/Au(0.5  $\mu\text{m}$ ) plating

### Phase (vs. frequency)



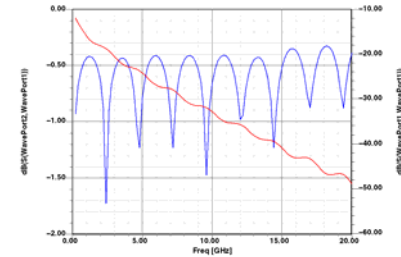
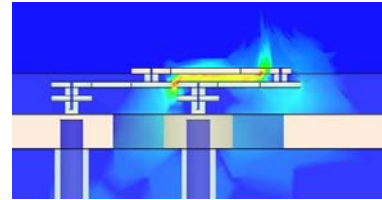
Drift of Effective Dk can be evaluated in millimeter wave band

## Influence of humidity absorption



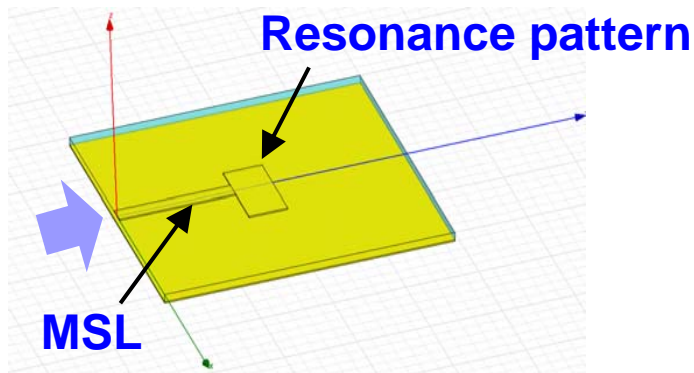
- 3D EM field solver (Ansys HFSS)
- Circuit simulator (Agilent ADS)

/ Guessing of electrical performance, combination of structures, and the most suitable materials

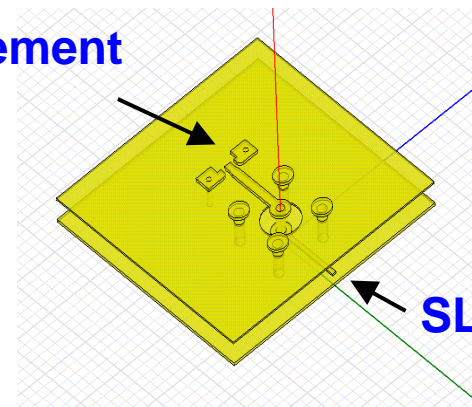


/ Designing of measurement terminals for evaluation of transmission properties to W-band, 100 GHz

/ Guessing of dielectric drift properties,  $\Delta Dk$ , by fitting calculated resonance properties,  $S_{11}$ , to measured  $S_{11}$



Measurement terminal



# Reliability of FX-2 (update)

Layer count : 24 layers

PCB thickness : 3.1 mm

Test temp.: 150°C +/- 3°C in 3 minutes

Criteria of failure: more than 10% change of resistance

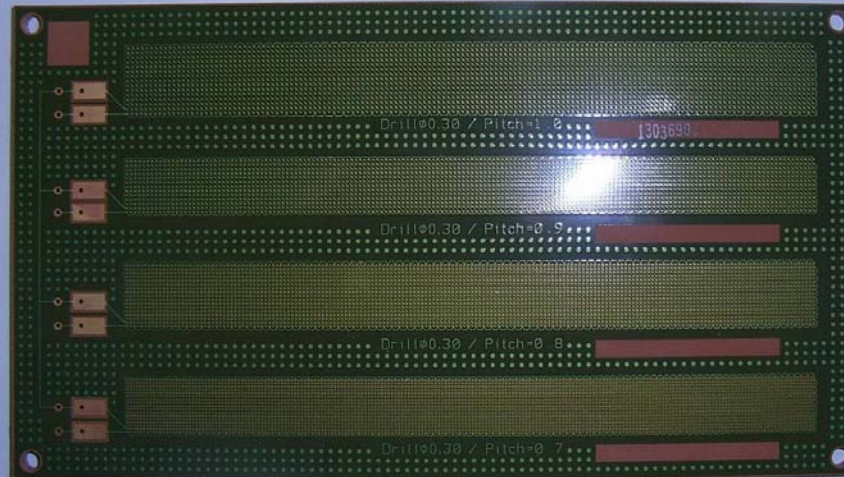
Drill hole size	Pre-conditioning	Cycles
0.010"	AS IS	> 1,000
	4X (260°C)	> 1,000
	6X (260°C)	> 1,000
0.0135"	AS IS	> 1,000
	4X (260°C)	> 1,000
	6X (260°C)	> 1,000

*n = 6pnl*

**Good through-hole connection reliability**

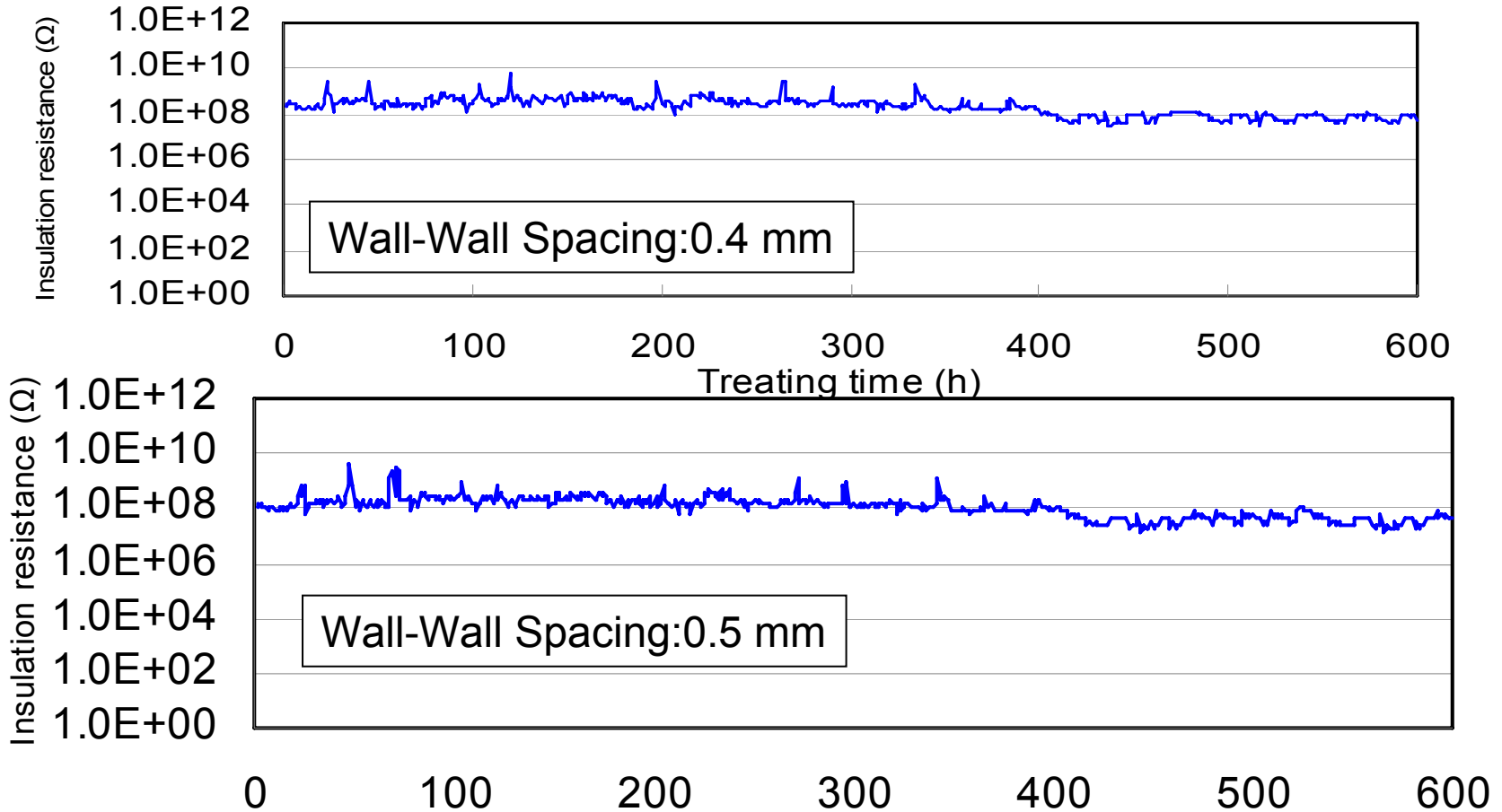
- / Total thickness: 4.1 mm (28 layer board)
- / Wall-Wall Spacing: 0.40 mm, 0.50 mm, about 2,000 holes
- / Precondition: 85°C/85%RH/120 h + Reflow 260°C X 10 times
- / Measurement condition: 85°C/85%RH DC100 V
- / The measurement of insulation resistance in chamber

## Hitachi Chemical original pattern



# Results of CAF evaluation

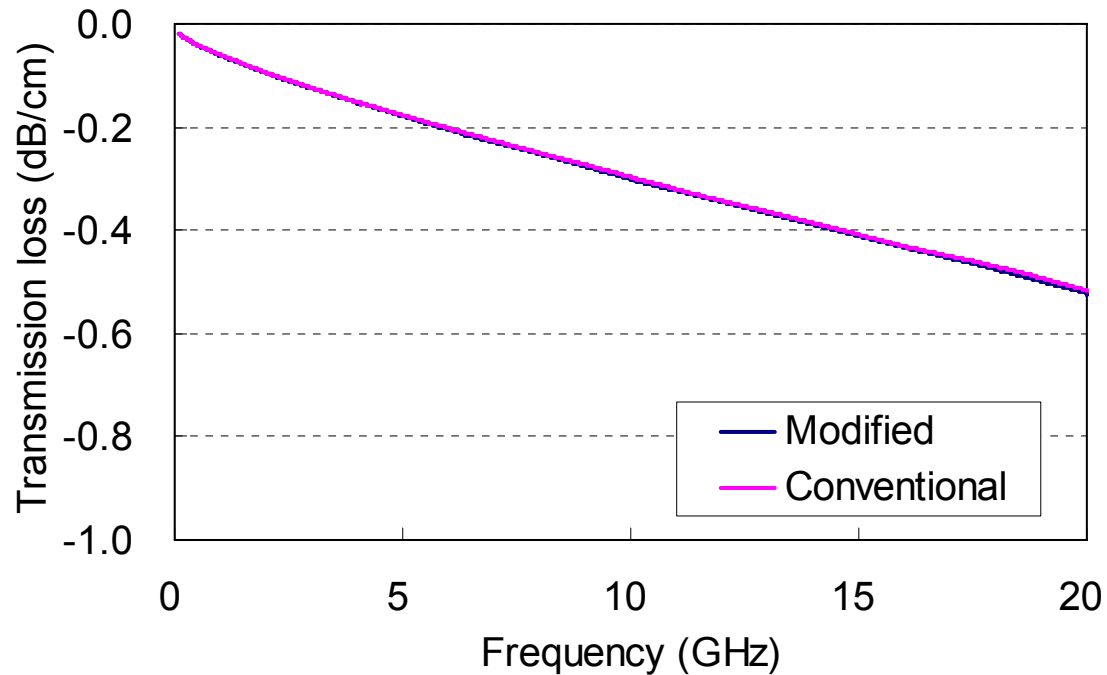
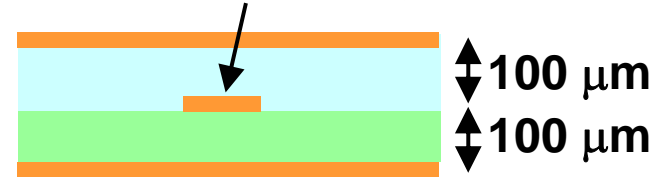
Measurement condition: 85°C/85%RH DC100V,  
The measurement of insulation resistance in chamber



**Good CAF restraining property**

**<Measurement condition>**  
/ Structure: Strip line  
/ Equipment: VNA  
/ Calibration: TRL

Line width: 180~200  $\mu\text{m}$   
Cu thickness: 18  $\mu\text{m}$



**Equal to conventional FX-2**



# Road map of Hitachi high frequency PWB materials

Applications		~2000	2002	2004	2006	2008	2010	2012	2014
Transmission rate/Link (Backplane)		300 Mbps~1 Gbps	1.25~2.5 Gbps	3.2~6.4 Gbps			~10 Gbps		>10 Gbps
(Mobile)		<2.4 kbps	9.6~144 kbps	2 Mbps	3.8 Mbps	5.7 Mbps	7.2 Mbps		>10 Mbps
High-end digital (High-speed & High-layer)	High-end Router		Dk<3.8/Df<0.005				Dk<3.7 Df<0.003		Dk<3.5 Df<0.002
	High-end Server Transport								
Super computer IC tester			LX-67/LX-67Y	LZ-71G		FX-2/FX-3		New Material or Opt ?	
	Measuring equipment		Dk:3.5/Df:0.005	Dk:3.6/Df:0.006		Dk:3.2-3.5/ Df:0.0025-0.0028			
BTS (Sgnl.-Pros.)									
Middle ~ Low digital (High-speed & High-layer)	Mobile devices	Dk<4.5/Df<0.025		Dk<4.5/Df<0.018		Dk<4.0/Df<0.01		Dk<3.8 Df<0.007	
	Low~Middle Router/Server								
BTS (Sgnl.-Pros.)		E-67/E-679	BE-67G(H)	E-679FJ	HE-679G	HE-679G(K)			
		Dk:>4.0/Df:>0.02	Dk:4.5/Df:0.01	Dk:4.3/Df:0.018	Dk:4.0/Df:0.009	Dk:3.7/Df:0.007			
RF/Wireless (Analog high-Freq.)	Antenna	Df<0.01		Df<0.005		Dk<3.5 Df<0.003		Dk<3.2 Df<0.002	
	Sensor								
RF-Module									
	Base station	HD-67	LX-67F			FX-2/FX-3	FX-4		
Mobile devices		Dk:10.2/Df:0.009	Dk:3.7/Df:0.003			Dk:3.2-3.5/ Df:0.0025-0.0028	Dk:3.2/ Df:0.0025		
	Satellite								
High-Freq. -PKG	Mobile devices			Df<0.015		Df<0.01		Df<0.005	
	RF-Module								
MMIC-PKG				E-679FG	LZ-71G	E-800G,Falcon	AS-Z5(BU)		
	OEIC-PKG			Dk:4.5/Df:0.014	Dk:3.6/Df:0.006	Dk:4.0/Df:0.005	Dk:3.1 /Df:0.004		

Dk&Df:@1GHz

- 1. Hitachi Chemical has various evaluation technology of dielectric properties and practical electrical properties.**
- 2. Hitachi Chemical intend to accelerate R&D of materials for next generation through these technology and newly constructed technology.**
- 3. We also would like to propose the combination of the most suitable materials depending on PCB structure and applications by using evaluation technology and simulation.**

# *Hitachi Chemical*

*Working On Wonders*

 **Hitachi Chemical Co., Ltd.**